

# Course Specifications

From the academic year 2015-2016 up to and including the academic year

# Physics of Semiconductor Technologies and Devices (E031521)

Due to Covid 19, the education and assessment methods may vary from the information displayed in the schedules and course details. Any changes will be communicated on Ufora.

| Course size  | (nominal values; actual value    | es may depend on prog | ramme)            |                  |          |       |
|--|----------------------------------|-----------------------|-------------------|------------------|----------|-------|
| Credits 4.0  | Credits 4.0 Study time 120 h     |                       | Contact hrs 36.0h |                  |          |       |
| Course offerings and   | l teaching methods in academic y | ear 2021-2022         |                   |                  |          |       |
| A (semester 2)   | English                          | Gent                  | pr                | oject            |          | 5.0h  |
|  |                                  |                       | le                | cture            |          | 30.0h |
|  |                                  |                       | pr                | acticum          |          | 5.0h  |
| B (semester 2)   | Dutch                            | Gent                  | pr                | oject            |          | 5.0h  |
|  |                                  |                       | pr                | acticum          |          | 5.0h  |
|  |                                  |                       | gu                | uided self-study |          | 30.0h |
| 0 (semester 2)   | English                          | Gent                  |                   |                  |          |       |
| Lecturers in academi   | ic year 2021-2022                |                       |                   |                  |          |       |
| Van Steenberge, Geert T  |                                  |                       | TW06              | lecturer-in-ch   | arge     |       |
| Missinne, Jeroe  | n                                |                       | TW06              | co-lecturer      |          |       |
| Vounckx, Roger   |                                  |                       | VUB               | co-lecturer      |          |       |
| Offered in the following programmes in 2021-2022   |                                  |                       |                   | crdts            | offering |       |
| Bridging Programme Master of Science in Photonics Engineering  |                                  |                       |                   | 4                | А        |       |
| Master of Science in Electrical Engineering (main subject Communication and Information                    |                                  |                       |                   | on 4             | А        |       |
| Technology )<br>Master of Science in Electromechanical Engineering(main subject Control Engineering and    |                                  |                       |                   | ind 4            | А        |       |
| Automation)  |                                  |                       |                   |                  |          |       |
| Master of Science in Electromechanical Engineering(main subject Electrical Power                           |                                  |                       |                   | 4                | А        |       |
| Engineering)<br>Master of Science in Electrical Engineering (main subject Electronic Circuits and Systems) |                                  |                       |                   | s) 4             | А        |       |
| Master of Science in Electromechanical Engineering(main subject Maritime Engineering)                      |                                  |                       |                   | -                | A        |       |
| Master of Science in Electromechanical Engineering(main subject Mechanical                                 |                                  |                       |                   | 4                | А        |       |
| Construction)  |                                  |                       |                   | ,                |          |       |
| Master of Science in Electromechanical Engineering(main subject Mechanical Energy<br>Engineering)          |                                  |                       |                   | 4                | А        |       |
| European Master of Science in Photonics  |                                  |                       |                   | 4                | А        |       |
| Master of Science in Photonics Engineering   |                                  |                       |                   | 4                | В        |       |
| Master of Science in Photonics Engineering   |                                  |                       |                   | 4                | A, 0     |       |

# Teaching languages

English, Dutch

# Keywords

technology, crystal growth, oxidation, photolithography, etching, diffusion, ion implantation, film deposition, photodetector, LED

#### Position of the course

This course describes the different processes involved in the fabrication of modern semiconductor components. The course is divided into two parts. The first part describes the physics of the different processing steps, while the second part describes the fabrication of the most important optical and optoelectronic components.

# Contents

Crystal Growth

- Silicon Crystal Growth from the Melt: Starting Material, The Czochralski Technique, Distribution of Dopant, Effective Segregation Coefficient
- Silicon Float-Zone Process
- GaAs Crystal Growth Techniques: Starting Materials, Crystal Growth Techniques
- Material Characterization: Wafer Shaping, Crystal Characterization

# Silicon Oxidation

- Thermal Oxidation Process: Kinetics of Growth, Thin Oxide Growth
- Impurity Redistribution During Oxidation
- Masking Properties of Silicon Dioxide
- Oxide Quality
- Oxide Thickness Characterization

# Photolithography

- Optical Lithography: The Clean Room, Exposure Tools, Masks, Photoresist, Pattern Transfer, Resolution Enhancement Techniques
- Next-Generation Lithographic Methods: Electron Beam Lithography, Extreme Ultraviolet Lithography, X-Ray Lithography, Ion Beam Lithography, Comparison of Various Lithographic Methods

# Etching

- Wet Chemical Etching: Silicon Etching, Silicon Dioxide Etching, Silicon Nitride and Polysilicon Etching, Aluminum Etching, Gallium Arsenide Etching
- Dry Etching: Plasma Fundamentals, Etch Mechanism, Plasma Diagnostics, and End-Point Control, Reactive Plasma Etching Techniques and Equipment, Reactive Plasma Etching Applications

# Diffusion

- Basic Diffusion Process: Diffusion Equation, Diffusion Profiles, Evaluation of Diffused Layers
- Extrinsic Diffusion: Concentration-Dependent Diffusivity, Diffusion Profiles
- Lateral Diffusion

# Ion Implantation

- Range of Implanted Ions: Ion Distribution, Ion Stopping, Ion Channeling
- Implant Damage and Annealing
- Implantation-Related Processes: Multiple Implantation and Masking, Tilt-Angle Ion Implantation, High-Energy and High-Current Implantation

# Film Deposition

- Epitaxial Growth Techniques: Chemical Vapor Deposition, Molecular Beam Epitaxy
- Structures and Defects in Epitaxial Layers: Lattice-Matched and Strained-Layer Epitaxy, Defects in Epitaxial Layers
- Dielectric Deposition: Silicon Dioxide, Silicon Nitride, Low-Dielectric-Constant Materials, High-Dielectric-Constant Materials
- Polysilicon Deposition
- Metallization: Physical Vapor Deposition, Chemical Vapor Deposition, Aluminum Metallization, Copper Metallization, Silicide

# Semiconductor Components

- Silicon Photodetectors
- Compound Semiconductor Photosensors
- Light Emitting Diodes

# Initial competences

basic knowledge of physics and solid-state physics

# **Final competences**

# KNOWLEDGE and INSIGHTS:

- Understanding of different process steps like crystal growth, oxidation, photolithography, etching, diffusion, ion implantation, and film deposition;
- Understanding of the basic operation and the fabrication of the most important optical and optoelectronic components.

SKILLS:

• Basic use of TCAD tools for process modelling;

- Critical reading and understanding of a scientific article;
- Hands-on experience with a number of process steps in a clean room environment.

#### Conditions for credit contract

Access to this course unit via a credit contract is determined after successful competences assessment

### Conditions for exam contract

This course unit cannot be taken via an exam contract

#### Teaching methods

Practicum, Guided self-study, Lecture, Project

# Extra information on the teaching methods

lectures; practicum, project.

# Learning materials and price

Syllabus (in English)

#### References

- G.S. May and S.M. Sze. Fundamentals of Semiconductor Fabrication, John Wiley and Sons, 2004.
- H. Zimmermann. Silicon Optoelectronic Integrated Circuits, Springer, 2004.
- C.Y. Chang and S.M. Sze. ULSI Technology, McGraw-Hill, 1996.
- C.Y. Chang and S.M. Sze. ULSI Devices, John Wiley and Sons, 2000.

#### Course content-related study coaching

4 researchers

#### Assessment moments

end-of-term and continuous assessment

#### Examination methods in case of periodic assessment during the first examination period

Oral examination

# Examination methods in case of periodic assessment during the second examination period

Oral examination

# Examination methods in case of permanent assessment

Report

#### Possibilities of retake in case of permanent assessment

not applicable

#### Extra information on the examination methods

During examination period: written closed-book exam complemented with oral examination; During semester: graded project reports.

# Calculation of the examination mark

Reports: 30%. examination: 70%